

Approved for use through 10/31/2002. OMB 0651-0031
U.S. Patent and Trademark Office: U.S. DEPARTMENT OF COMMERCE
control number.

Substitute for form 1449B/PTO

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(use as many sheets as necessary) Sheet of

Complete if Known				
Application Number	10/707,474			
Filing Date	12/17/2003	•		
First Named Inventor	Ching-Hsiang Hsu	f Sc		
Group Art Unit	28/8	1		
Examiner Name	TRONG PHAN			
Attomey Docket Number				

Examiner Initials	Cite No. ¹	OTHER PRIOR ART — NON PATENT LITERATURE DOCUMENTS Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T			
7P	1	C.CH. HSU, et al.; A High Speed, Low Power P-Channel Flash EEPROM Using Silicon Rich Oxide as Tunneling Dielectric; Extended Abstracts of the 1992 International Conference on Solid State Device and Materials, Tsukuba, 1992, pp. 140-142				
	,					
, .	1 -					
1	···					
•						
	 		•			
.						

			-		
Examiner	Trans	Phase	Date	Eli lai	
Signature	Trong	Man	Considered	3/4/04	•

^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. include copy of this form with next communication to applicant.

¹ Applicant's unique citation designation number (optional). ² Applicant is to place a check mark here if English language Translation is attached.

Burden Hour Statement: This form is estimated to take 2.0 hours to complete. Time will vary depending upon the needs of the individual case. Any comments on the amount of time you are required to complete this form should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, Washington, DC 20231. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Assistant Commissioner for Patents, Washington, DC 20231.